

SOT-89 Plastic-Encapsulate Transistors

Features

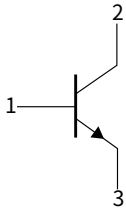
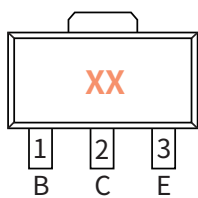
- Complementary to 2SB1132
- Power dissipation of 500mW
- High stability and high reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

Mechanical Data

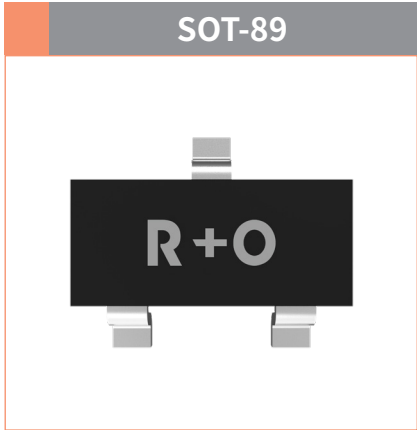
- Case: SOT-89
Molding compound meets UL 94V-0 flammability rating, RoHS-compliant,halogen-free
- Terminals: Solder plated, solderable per MIL-STD-750,Method 2026

Function Diagram

XX=Device Code
DAP=2SD1664-P
DAQ=2SD1664-Q
DAR=2SD1664-R



Collector-Base Voltage
VCBO 40V
Collector Current
1 Ampere



Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Collector-Base Voltage	V_{CBO}	V	40
Collector-Emitter Voltage	V_{CEO}		32
Emitter-Base Voltage	V_{EBO}		5.0
Collector Current	I_C	A	1.0
Collector Power Dissipation	P_C	mW	0.5
Storage temperature	T_{stg}	°C	-55 ~+150
Junction temperature	T_j	°C	150
Typical Thermal Resistance	$R_{\theta J-A}$	°C /W	250

Electrical Characteristics (Ta=25°C Unless otherwise noted)

PARAMETER	SYMBOL	UNIT	Condition	Min	Typ	Max
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	V	$I_C=50\mu A, I_E=0$	40	—	—
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$		$I_C=1.0mA, I_B=0$	32	—	—
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$		$I_E=50\mu A, I_C=0$	5.0	—	—
Collector-Base cut-off current	I_{CBO}	μA	$V_{CB}=20V, I_E=0$	—	—	0.5
Emitter-Base cut-off current	I_{EBO}		$V_{EB}=4.0V, I_C=0$	—	—	0.5
DC Current Gain	h_{FE}	V	$I_C=100mA, V_{CE}=3.0V$	82		390
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V	$I_C=500mA, I_B=50mA$	—	0.15	0.4
Collector output capacitance	C_{ob}	pF	$V_{CB}=10V, I_E=0, f=1MHz$	—	15	—

● Classification Of h_{FE}

RANK	P	Q	R
Range	82-180	120-270	180-390

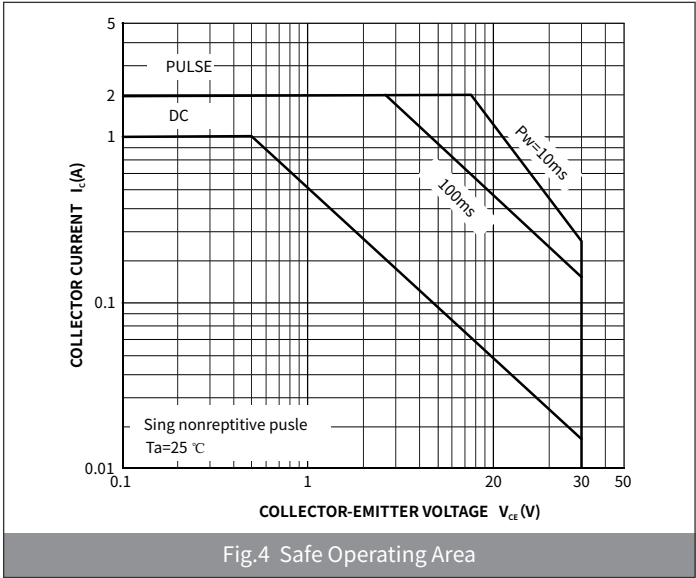
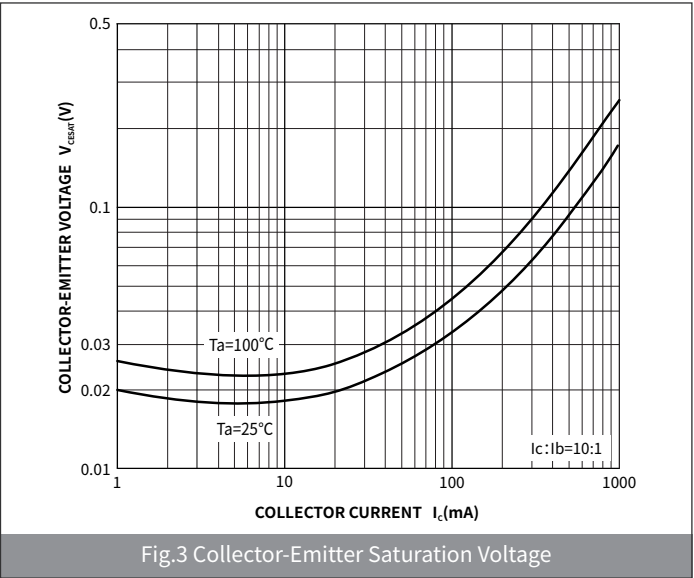
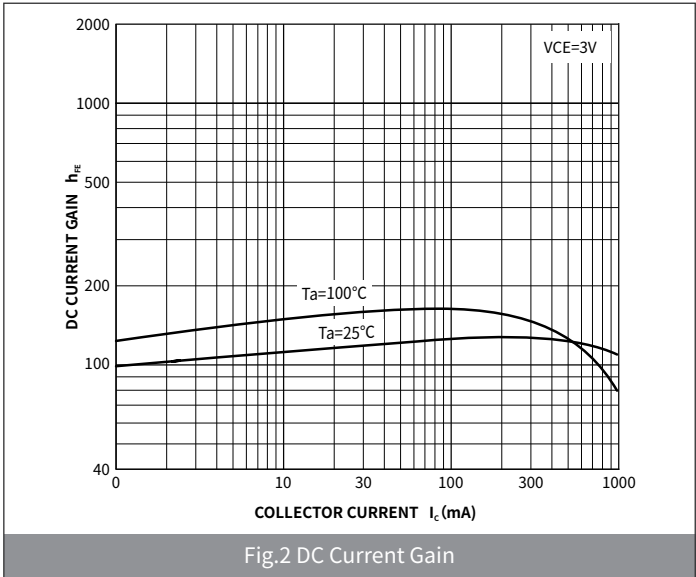
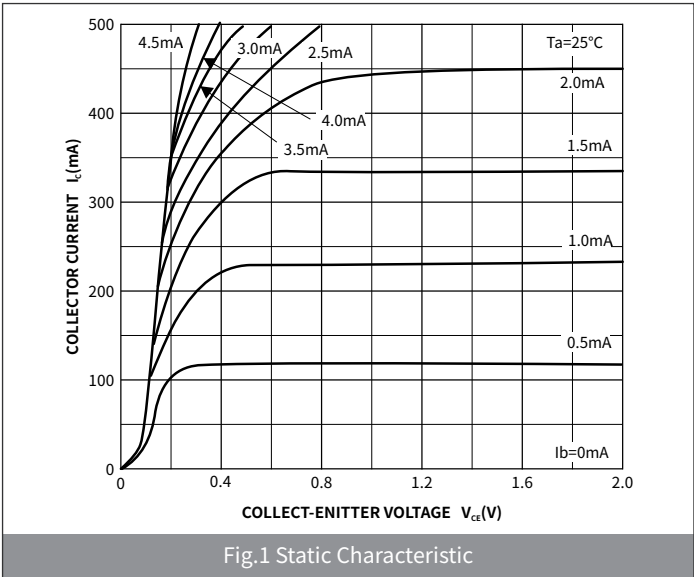
● Small-signal Characteristics

ITEM	SYMBOL	Condition	UNIT	Min	Tye	Max
Transition frequency	f_T	$I_C = -50\text{mA}$, $V_{CE} = -5\text{V}$	MHz	—	150	—

● Ordering Information

PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOT-89	R1	0.055	1000	7000	21000	7"

● Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



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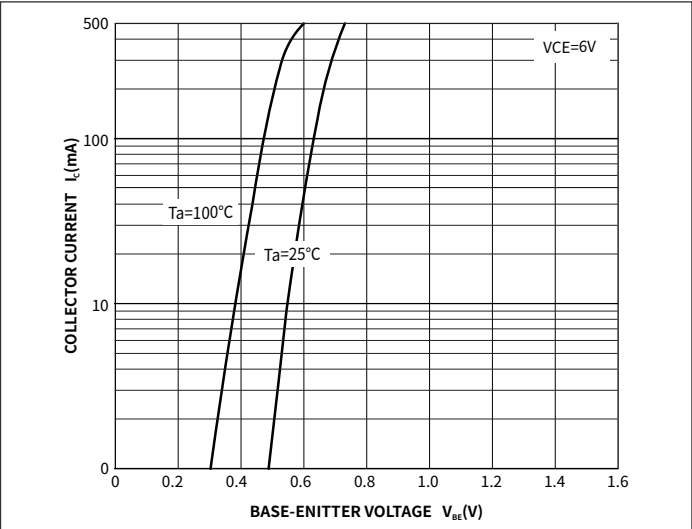


Fig.5 Base-Emitter On Voltage

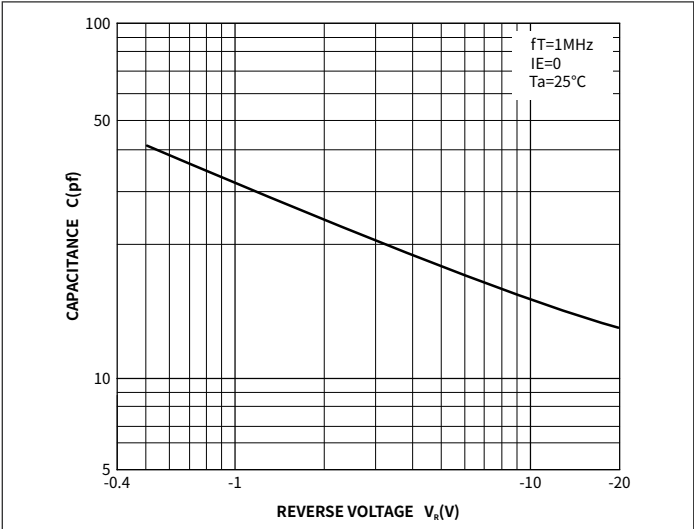
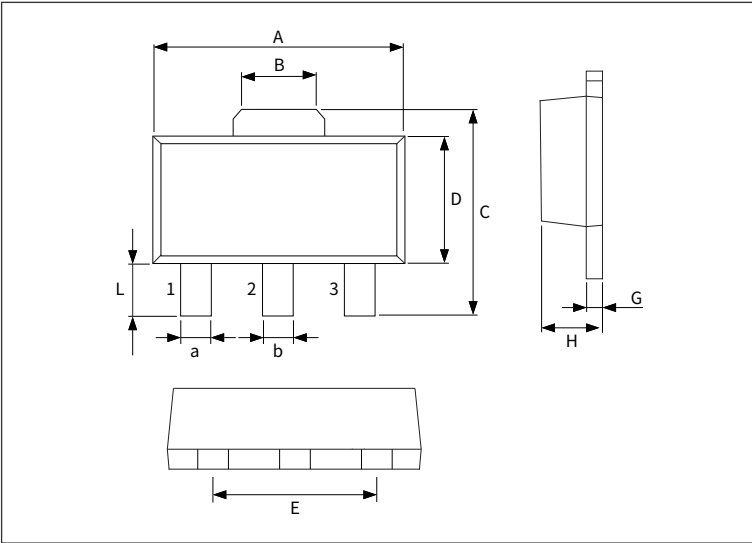


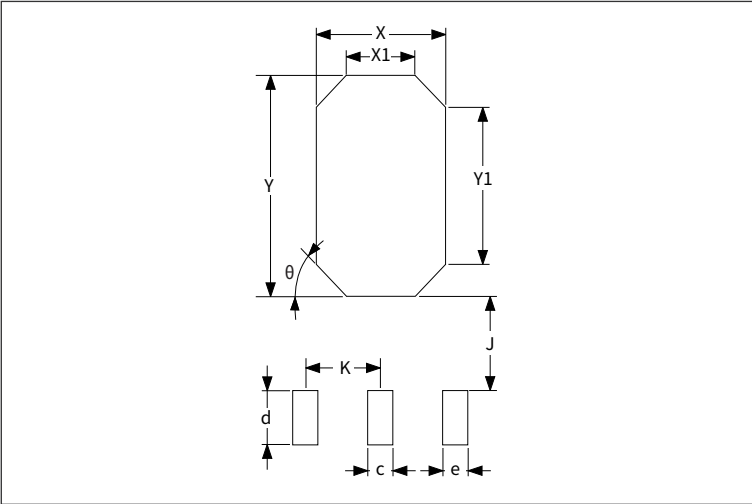
Fig.6 Cob/Cib- $V_{CB}V_{EB}$

● Package Outline Dimensions (SOT-89)



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.176	0.184
B	1.6	1.8	0.064	0.072
C	3.9	4.1	0.156	0.164
D	2.4	2.6	0.096	0.104
E	2.9	3.1	0.116	0.124
a	0.41	0.43	0.0164	0.018
b	0.35	0.45	0.014	0.018
L	0.95	1.05	0.037	0.041
G	0.3	0.5	0.012	0.020
H	1.4	1.5	0.055	0.059

● Suggested Pad Layout



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
c	0.80	1.00	0.032	0.04
d	1.30	1.50	0.052	0.060
e	0.70	0.90	0.028	0.036
J	1.80	2.00	0.072	0.080
K	1.40	1.60	0.056	0.064
X	2.50	2.70	0.100	0.108
X1	1.30	1.50	0.052	0.060
Y	4.30	4.50	0.172	0.180
Y1	3.10	3.30	0.124	0.132
θ	-	45°	-	45°